

Description

The DMG1013T uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

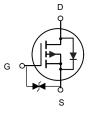


SOT-523

General Features

 $V_{DS} = -20V I_{D} = -0.66A$

$$\begin{split} R_{DS(ON)} < 560 &\,\mathrm{m}\Omega @~V_{GS} \text{=-}4.5V \\ R_{DS(ON)} < 780 &\,\mathrm{m}\Omega @~V_{GS} \text{=-}2.5V \\ ESD &~Rating:~1500V HBM \end{split}$$



Application

Battery protection

Load switch

Uninterruptible power supply

P-Channel MOSFET

Package Marking and Ordering Information

| Product ID | Pack | Brand | Qty(PCS) |
|------------|---------|------------|----------|
| DMG1013T | SOT-523 | HXY MOSFET | 3000 |

Absolute Maximum Ratings (T_A=25 ℃ unless otherwise noted)

| Symbol | Parameter | Limit | Unit |
|-----------------|--------------------------------------------------|------------|------------|
| V _{DS} | Drain-Source Voltage | -20 | V |
| Vgs | Gate-Source Voltage | ±12 | V |
| I _D | Drain Current-Continuous | -0.66 | А |
| P _D | Maximum Power Dissipation | 150 | mW |
| Тл,Тятв | Operating Junction and Storage Temperature Range | -55 To 150 | $^{\circ}$ |
| Reja | Thermal Resistance,Junction-to-Ambient (Note 2) | 833 | °C/W |



Electrical Characteristics (T_J=25°C, unless otherwise noted)

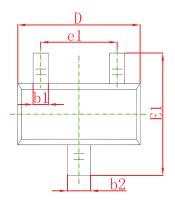
| Parameter | Symbol | Test conditions | Min | Тур | Max | Unit | |
|-------------------------------------------------------------|----------------------|-----------------------------------------------------------|------|------|------|------|--|
| STATIC CHARACTERISTICE | | | | | | | |
| Drain-source breakdown voltage | V _{(BR)DSS} | V _{GS} = 0V, I _D =-250µA | -20 | | | V | |
| Zero gate voltage drain current | I _{DSS} | V _{DS} =-20V,V _{GS} = 0V | | | -1 | μΑ | |
| Gate-body leakage current | I _{GSS} | V _{GS} =±10V, V _{DS} = 0V | | | ±10 | μΑ | |
| Gate threshold voltage (note2) | $V_{\text{GS(th)}}$ | V _{DS} =V _{GS} , I _D =-250µA | -0.4 | -0.7 | -1.0 | V | |
| Drain-source on-resistance (note2) | R _{DS(on)} | V _{GS} =-4.5V, I _D =-0.5A | | | 0.56 | Ω | |
| | | V _{GS} =-2.5V, I _D =-0.2A | | | 0.78 | Ω | |
| Maximum Continuous Drain to Source Diode Forward Current | Is | | | | -0.6 | А | |
| Maximum Pulsed Drain to Source Diode Forward Current | Іѕм | | | | -1.2 | А | |
| Diode forward voltage | V _{SD} | I _S =-0.5A, V _{GS} = 0V | | | -1.2 | V | |
| DYNAMIC CHARACTERISTICS (note4) | | | | | | | |
| Input capacitance | C _{iss} | V _{DS} =-16V,V _{GS} =0V, | | 115 | | pF | |
| Output capacitance | Coss | | | 15 | | pF | |
| Reverse transfer capacitance | C _{rss} | 1 - 11VII 12 | | 9 | | pF | |
| SWITCHING CHARACTERISTICS (note4) | | | | | | | |
| Turn-on delay time (note3) | t _{d(on)} | | | 9 | | nS | |
| Turn-on rise time (note3) | t _r | V _{GS} =-4.5V,V _{DS} =-10V, | | 6 | | nS | |
| Turn-off delay time (note3) | t _{d(off)} | I_D =-200mA, R_{GEN} =10 Ω | | 33 | | nS | |
| Turn-off fall time (note3) | t _f | | | 22 | | nS | |

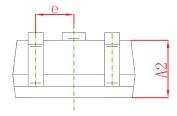
Notes:

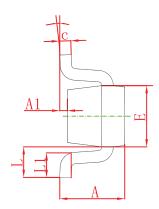
- 1. Surface mounted on FR4 board using the minimum recommended pad size.
- 2. Pulse Test : Pulse Width=300 μ s, Duty Cycle=2%.
- 3. Switching characteristics are independent of operating junction temperatures.
- 4. Guaranteed by design, not subject to producting.



SOT-523 Package Information

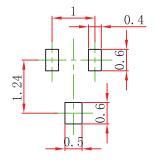






| Symbol | Dimensions In Millimeters | | Dimensions In Inches | | |
|--------|---------------------------|-------------------|----------------------|-------|--|
| | Min. | Max. | Min. | Max. | |
| Α | 0.700 | 0.900 | 0.028 | 0.035 | |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 | |
| A2 | 0.700 | 0.800 | 0.028 | 0.031 | |
| b1 | 0.150 | 0.250 | 0.006 | 0.010 | |
| b2 | 0.250 | 0.350 | 0.010 | 0.014 | |
| С | 0.100 | 0.200 | 0.004 | 0.008 | |
| D | 1.500 | 1.700 | 0.059 | 0.067 | |
| E | 0.700 | 0.900 | 0.028 | 0.035 | |
| E1 | 1.450 | 1.750 | 0.057 | 0.069 | |
| е | 0.500 |) TYP. 0.020 TYP. | | TYP. | |
| e1 | 0.900 | 1.100 | 0.035 | 0.043 | |
| L | 0.400 REF. | | 0.016 REF. | | |
| L1 | 0.260 | 0.460 | 0.010 | 0.018 | |
| θ | 0° | 8° | 0° | 8° | |

SOT-523 Suggested Pad Layout



Note:

- 1. Controlling dimension: in millimeters.
- 2.General tolerance:±0.05mm.
- 3. The pad layout is for reference purposes only.



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